

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	364	(plasma adj polymer\$6 adj methylsilane) or PPMS <i>PPMS</i> <i>(positive near mask\$6)</i>	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
2	BRS	L2	42892	<i>Organosilicon</i> <i>photoresist</i> DUV or ((ultraviolet or ultra-violet or (ultra adj violet)) adj radiat\$6) <i>or mask + \$6 or light</i> <i>or electron\$6</i>	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
3	BRS	L3	793504	trench\$4 or interconnect\$6 or damascene	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
4	BRS	L4	493786 3	PPMSO or oxygen or O or oxidiz\$6	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
5	BRS	L5	297694	DRAM or SRAM or SDRAM or FLASH	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B

PR on resist

	Type	L #	Hits	Search Text	DBs
6	BRS	L6	9	1 near8 2	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
7	BRS	L7	7	1 same 2 same 3	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
8	BRS	L8	12	1 same 2	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
9	BRS	L9	21	1 and 2	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
10	BRS	L10	29	1 and 5	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	364	(plasma adj polymer\$6 adj methylsilane) or PPMS	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:16
2	BRS	L2	42892	DUV or ((ultraviolet or ultra-violet or (ultra adj violet)) adj radiat\$6)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:16
3	BRS	L3	493786 3	PPMSO or oxygen or O or oxidiz\$6	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:16
4	BRS	L4	9	((plasma adj polymer\$6 adj methylsilane) or PPMS) near8 (DUV or ((ultraviolet or ultra-violet or (ultra adj violet)) adj radiat\$6))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:16
5	BRS	L5	7	((plasma adj polymer\$6 adj methylsilane) or PPMS) same (DUV or ((ultraviolet or ultra-violet or (ultra adj violet)) adj radiat\$6)) same (trench\$4 or interconnect\$6 or damascene)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:17

	Type	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L6	12	((plasma adj polymer\$6 adj methylsilane) or PPMS) same (DUV or ((ultraviolet or ultra-violet or (ultra adj violet)) adj radiat\$6))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:17
7	BRS	L7	21	((plasma adj polymer\$6 adj methylsilane) or PPMS) and (DUV or ((ultraviolet or ultra-violet or (ultra adj violet)) adj radiat\$6))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:17
8	BRS	L8	29	((plasma adj polymer\$6 adj methylsilane) or PPMS) and (DRAM or SRAM or SDRAM or FLASH)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:17
9	BRS	L9	92017	positiv\$6 near8 (mask\$6 or resist\$4 or PR or photoresist\$3 or photo-resist\$3 or (organo adj silicon) or organosilicon or photodefinable or photo-definable)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:17
10	BRS	L10	365152 2	DUV or UV or radiat\$6 or light\$6 or electromag\$6	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:18

	Type	L #	Hits	Search Text	DBs	Time Stamp
11	BRS	L11	17874	(positiv\$6 near8 (mask\$6 or resist\$4 or PR or photoresist\$3 or photo-resist\$3 or (organo adj silicon) or organosilicon or photodefinable or photo-definable)) same (DUV or UV or radiat\$6 or light\$6 or electromag\$6)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:43
12	BRS	L12	7338	(positiv\$6 near8 (mask\$6 or resist\$4 or PR or photoresist\$3 or photo-resist\$3 or (organo adj silicon) or organosilicon or photodefinable or photo-definable)) near8 (DUV or UV or radiat\$6 or light\$6 or electromag\$6)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:18
13	BRS	L13	364	(plasma adj polymer\$6 adj methylsilane) or PPMS or PPMSS	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:41
14	BRS	L14	793504	trench\$4 or interconnect\$6 or damascene	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:18
15	BRS	L15	297694	DRAM or SRAM or SDRAM or FLASH	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:18

	Type	L #	Hits	Search Text	DBs	Time Stamp
16	BRS	L16	439	((positiv\$6 near8 (mask\$6 or resist\$4 or PR or photoresist\$3 or photo-resist\$3 or (organo adj silicon) or organosilicon or photodefinable or photo-definable)) same (DUV or UV or radiat\$6 or light\$6 or electromag\$6)) same (trench\$4 or interconnect\$6 or damascene)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:19
17	BRS	L17	79	((positiv\$6 near8 (mask\$6 or resist\$4 or PR or photoresist\$3 or photo-resist\$3 or (organo adj silicon) or organosilicon or photodefinable or photo-definable)) same (DUV or UV or radiat\$6 or light\$6 or electromag\$6)) same (trench\$4 or interconnect\$6 or damascene)) and (DRAM or SRAM or SDRAM or FLASH)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:19

	Type	L #	Hits	Search Text	DBs	Time Stamp
18	BRS	L18	360	((positiv\$6 near8 (mask\$6 or resist\$4 or PR or photoresist\$3 or photo-resist\$3 or (organo adj silicon) or organosilicon or photodefinable or photo-definable)) same (DUV or UV or radiat\$6 or light\$6 or electromag\$6)) same (trench\$4 or interconnect\$6 or damascene)) not (((positiv\$6 near8 (mask\$6 or resist\$4 or PR or photoresist\$3 or photo-resist\$3 or (organo adj silicon) or organosilicon or photodefinable or photo-definable)) same (DUV or UV or radiat\$6 or light\$6 or electromag\$6)) same (trench\$4 or interconnect\$6 or damascene)) and (DRAM or SRAM or SDRAM or FLASH))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:19
19	BRS	L19	5	("4921321" "4978594" "5215861" "5439780" "5885751").PN.	USPAT	2004/01/14 10:19
20	BRS	L24	1	18 and 13	USPAT	2004/01/14 10:41
21	BRS	L25	364	(plasma adj polymer\$6 adj methylsilane) or PPMS or PPMSs or PPMSO or PPMSOs	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:42
22	BRS	L26	14	11 and 25	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/14 10:43

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	92017	positiv\$6 near8 (mask\$6 or resist\$4 or PR or photoresist\$3 or photo-resist\$3 or (organo adj silicon) or organosilicon or photodefinable or photo-definable)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:12
2	BRS	L2	365152 2	DUV or UV or radiat\$6 or light\$6 or electromag\$6	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:13
3	BRS	L3	17874	1 same 2	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:13
4	BRS	L4	7338	1 near8 2	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:13
5	BRS	L5	364	(plasma adj polymer\$6 adj methylsilane) or PPMS or PPMSS	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:14

	Type	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L6	793504	trench\$4 or interconnect\$6 or damascene	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:14
7	BRS	L7	297694	DRAM or SRAM or SDRAM or FLASH	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:18
8	BRS	L8	439	3 same 6	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:19
9	BRS	L9	79	8 and 7	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:20
10	BRS	L10	360	8 not 9	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/01/13 18:20

	Type	L #	Hits	Search Text	DBs
1	IS&R	L15	2536	(257/758) .CCLS.	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB
2	IS&R	L16	833	(257/762) .CCLS.	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB
3	IS&R	L17	1900	(257/773) .CCLS.	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB
4	IS&R	L18	1774	(257/774) .CCLS.	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB